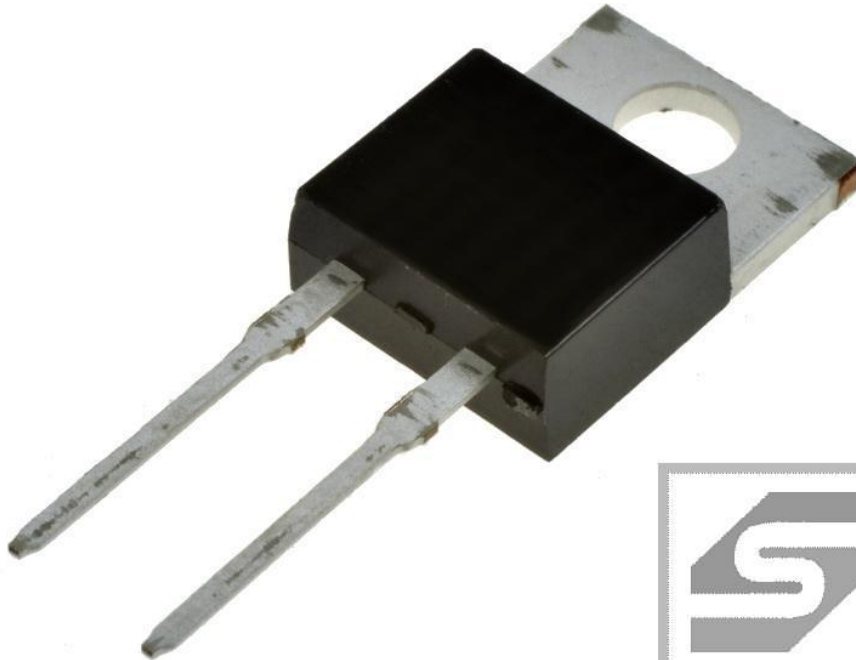




# Dioda Schottky MBR10100G LGE DO220 10A;100V;RoHS



## Dane techniczne:

Nazwa: MBR10100G

Typ diody: prostownicza Schottky

Napięcie wsteczne maksymalne: 100V

Napięcie przewodzenia maksymalne: 0.95V

Prąd przewodzenia diody: 10A

Prąd wsteczny: 100mA

Prąd udarowy przewodzenia: 150A

Obudowa: DO220

Montaż: przewlekany(THT)

# MBR1060, MBR1080, MBR1090, MBR10100

MBR1060 and MBR10100 are Preferred Devices

## SWITCHMODE™ Power Rectifiers

This series of SWITCHMODE power rectifiers uses the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

### Features

- Pb-Free Packages are Available\*
- Guard-Ring for Stress Protection
- Low Forward Voltage
- 150°C Operating Junction Temperature
- Epoxy Meets UL 94, V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction

### Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



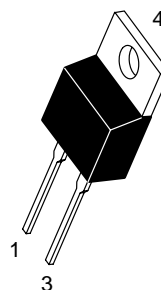
**ON Semiconductor®**

<http://onsemi.com>

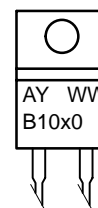
## SCHOTTKY BARRIER RECTIFIERS 10 AMPERES 60 to 100 VOLTS



### MARKING DIAGRAM



TO-220AC  
CASE 221B  
PLASTIC



A = Assembly Location  
Y = Year  
WW = Work Week  
B10x0 = Device Code  
x = 6, 8, 9 or 10

### ORDERING INFORMATION

Device	Package	Shipping
MBR1060	TO-220	50 Units/Rail
MBR1060G	TO-220 (Pb-Free)	50 Units/Rail
MBR1080	TO-220	50 Units/Rail
MBR1090	TO-220	50 Units/Rail
MBR1090G	TO-220 (Pb-Free)	50 Units/Rail
MBR10100	TO-220	50 Units/Rail
MBR10100G	TO-220 (Pb-Free)	50 Units/Rail

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**Preferred** devices are recommended choices for future use and best overall value.

# MBR1060, MBR1080, MBR1090, MBR10100

## MAXIMUM RATINGS

Rating	Symbol	MBR				Unit
		1060	1080	1090	10100	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	60	80	90	100	V
Average Rectified Forward Current (Rated $V_R$ ) $T_C = 133^\circ\text{C}$	$I_{F(AV)}$	10				A
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 kHz) $T_C = 133^\circ\text{C}$	$I_{FRM}$	20				A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	$I_{FSM}$	150				A
Peak Repetitive Reverse Surge Current (2.0 $\mu\text{s}$ , 1.0 kHz)	$I_{RRM}$	0.5				A
Operating Junction Temperature	$T_J$	-65 to +150				$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-65 to +175				$^\circ\text{C}$
Voltage Rate of Change (Rated $V_R$ )	$dv/dt$	10,000				V/ $\mu\text{s}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS

Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.0	$^\circ\text{C/W}$
Maximum Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	60	$^\circ\text{C/W}$

## ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 1) ( $i_F = 10$ Amps, $T_C = 125^\circ\text{C}$ ) ( $i_F = 10$ Amps, $T_C = 25^\circ\text{C}$ ) ( $i_F = 20$ Amps, $T_C = 125^\circ\text{C}$ ) ( $i_F = 20$ Amps, $T_C = 25^\circ\text{C}$ )	$v_F$	0.7 0.8 0.85 0.95	V
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_C = 125^\circ\text{C}$ ) (Rated dc Voltage, $T_C = 25^\circ\text{C}$ )	$i_R$	6.0 0.10	mA

1. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

# MBR1060, MBR1080, MBR1090, MBR10100

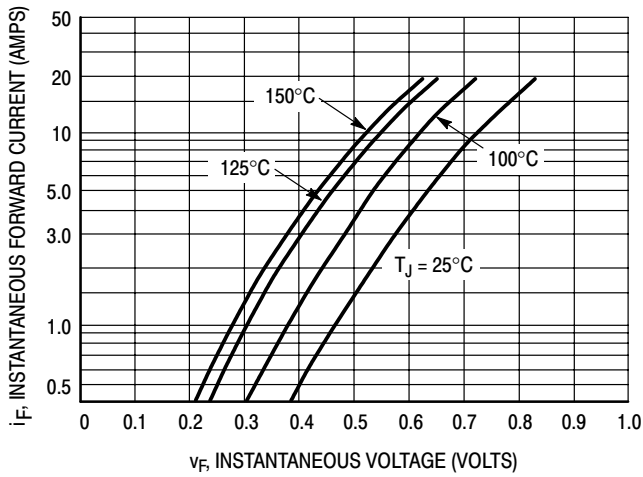


Figure 1. Typical Forward Voltage

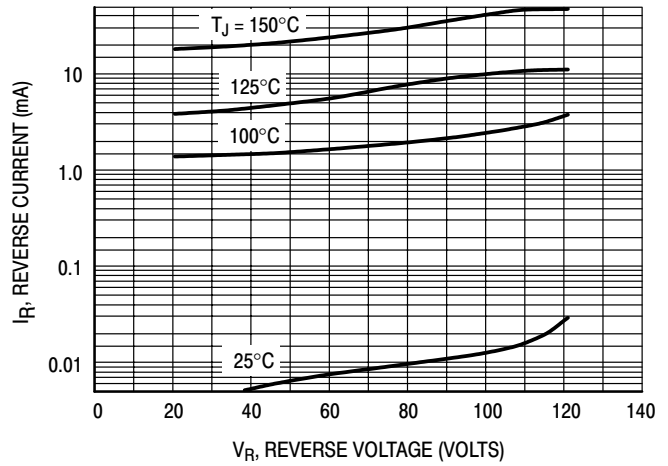


Figure 2. Typical Reverse Current

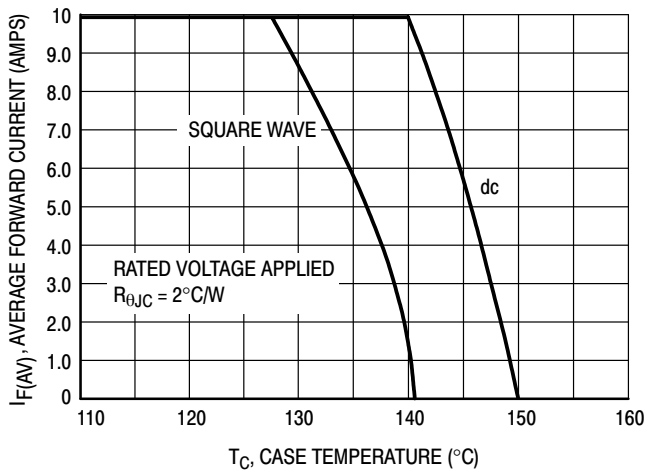


Figure 3. Current Derating, Case

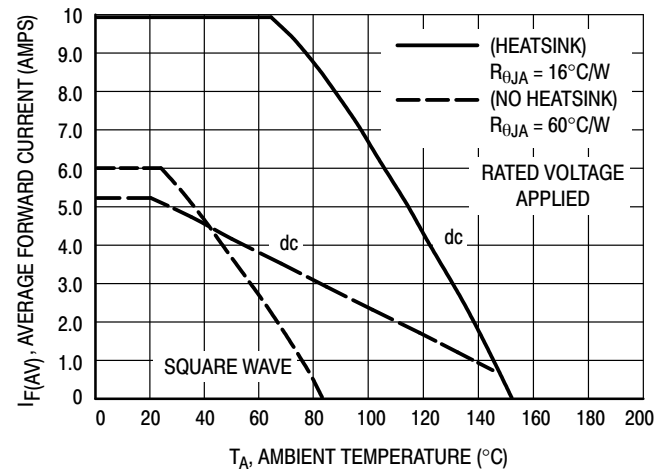


Figure 4. Current Derating, Ambient

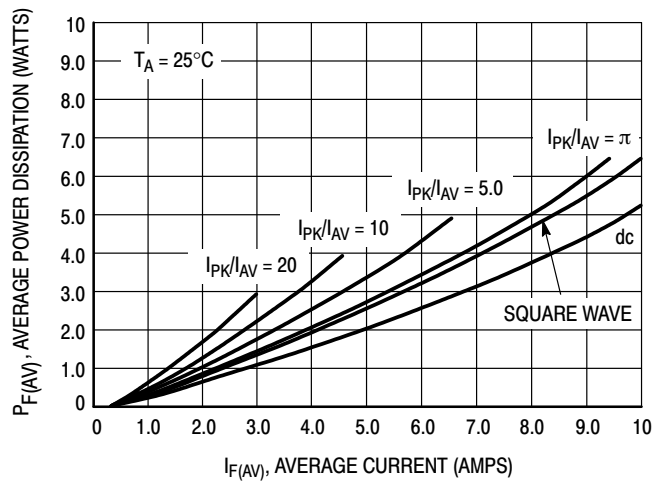
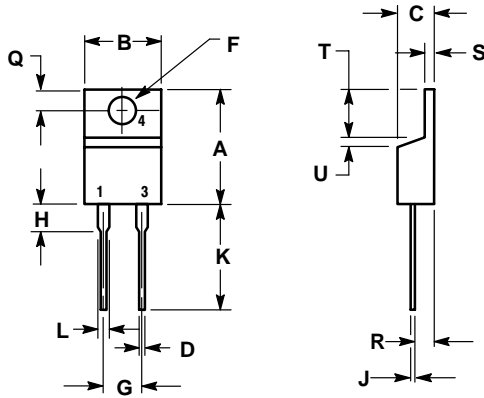


Figure 5. Forward Power Dissipation

# MBR1060, MBR1080, MBR1090, MBR10100

## PACKAGE DIMENSIONS

### TO-220 PLASTIC CASE 221B-04 ISSUE D




#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.595	0.620	15.11	15.75
B	0.380	0.405	9.65	10.29
C	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.190	0.210	4.83	5.33
H	0.110	0.130	2.79	3.30
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

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